Panasonic

DZ4J330K0R

Zener Diode

Silicon epitaxial planar type

Unit: mm 2.0 For constant voltage / For surge absorption circuit <u>0. 3</u> 0 13 4 Features Excellent rising characteristics of zener current Iz 25 Low zener operating resistance Rz Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant) 2 1 0.7 Marking Symbol: HG (0.65)(0.65) Basic Part Number : 1.3 Dual DZ2J330 (Parallel) Packaging 3. Cathode-2 1. Anode-1 Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard) 4. Cathode-1 2. Anode-2 Panasonic SMini4-F3-B Absolute Maximum Ratings Ta = 25 °C JEITA SC-113BB Parameter Unit Code Symbol Rating 200 Repetitive peak forward current IFRM mΑ

Total power dissipation ^{*1}	PT	200	mW
Electrostatic discharge ^{*2}	ESD	±8	kV
Junction temperature	Tj	150	С°
Operating ambient temperature	Topr	-40 to +85	С°
Storage temperature	Tstg	-55 to +150	С°

Note) *1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm) Solder in (0.8 mm x 0.8 mm)

*2: Test method:IEC61000_4_2(C = 150 pF,R = 330 Ω , Contact discharge:10 times)

Internal Connection

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 2 mA	31.35		34.65	V
Zener operating resistance	RZ	IZ = 2 mA			200	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			200	Ω
Reverse current	IR	VR = 25 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 2 mA		32.0		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. Absolute frequency of input and output is 5 MHz.

■ Electrical Characteristics Ta = 25 °C ± 3 °C

 *1: The temperature must be controlled 25 °C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ (25 °C)

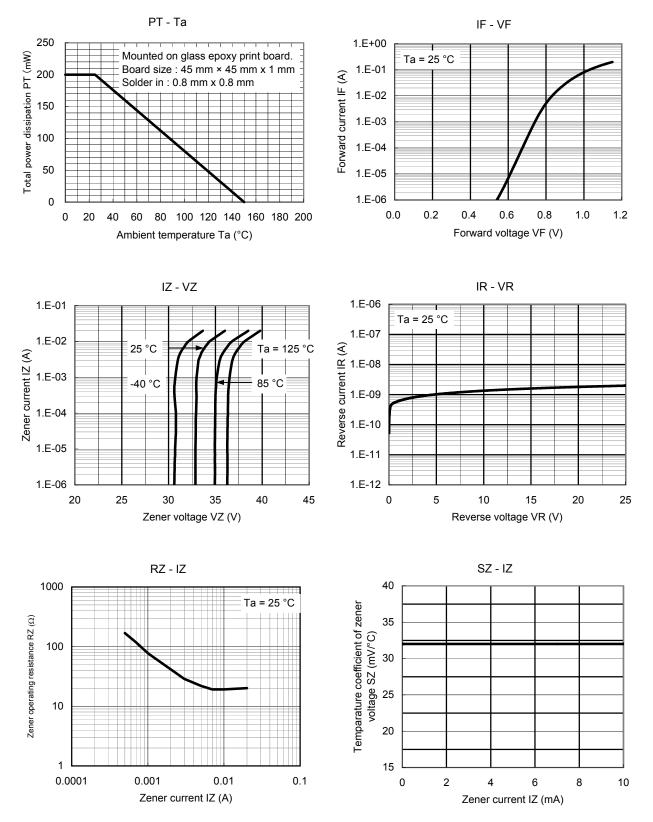
*2: VZ guaranted 20 ms after current flow.

*3: Tj = 25 °C to 150 °C



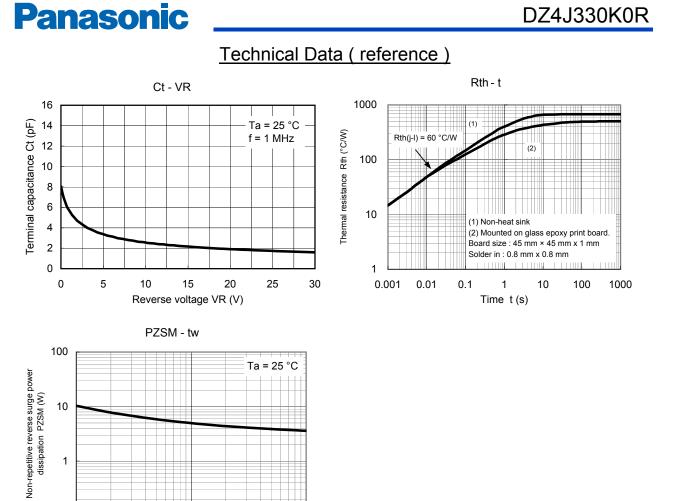
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Technical Data (reference)



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Established : 2009-12-21 Revised : 2013-10-07



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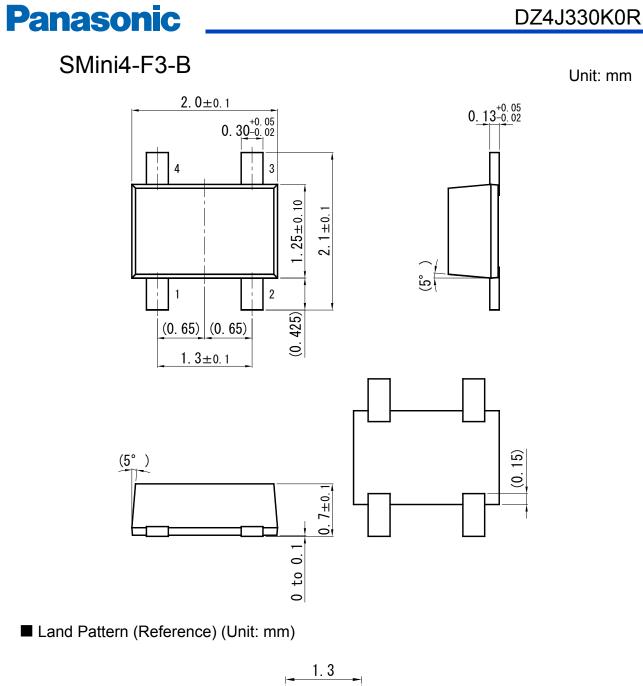
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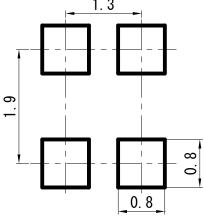
Zener Diode

0.1 └ 100

1000

Pulse width tw (µs)





Zener Diode

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